





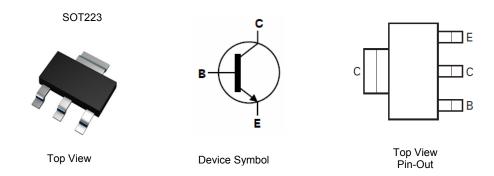
#### 60V NPN SILICON PLANAR HIGH PERFORMANCE TRANSISTOR IN SOT223

#### **Features**

- BV<sub>CEO</sub> > 60V
- Maximum continuous current I<sub>C</sub> = 3A
- Low Saturation Voltage
- Complementary PNP Type FZT751
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

#### **Mechanical Data**

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (approximate)



#### Ordering Information (Notes 4 & 5)

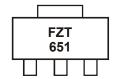
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT651TA	AEC-Q101	FZT651	7	12	1,000
FZT651QTA	Automotive	FZT651	7	12	1,000
FZT651TC	AEC-Q101	FZT651	13	12	4,000
FZT651QTC	Automotive	FZT651	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

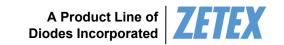
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- 4.1000ppm antimony compounds.
   4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally
- the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com

### **Marking Information**



FZT651 = Product Type Marking Code





# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	3	Α
Peak Pulse Current	I <sub>CM</sub>	6	Α

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	В	2	W
Power Dissipation	(Note 7)	P <sub>D</sub>	3	W
Thermal Resistance, Junction to Ambient	(Note 6)	р	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	$-$ R <sub><math>\theta</math>JA</sub>	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 8	$R_{\theta JL}$	12.93	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

### ESD Ratings (Note 9)

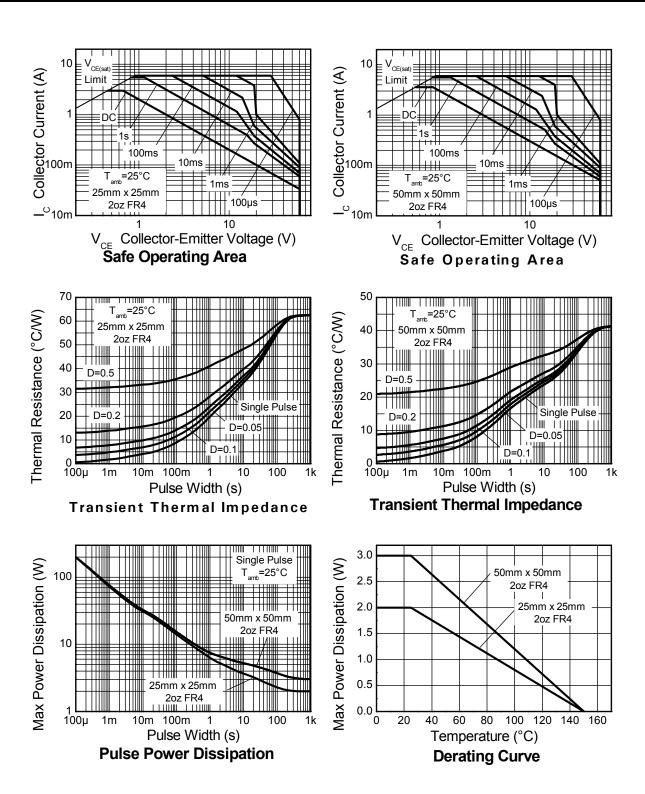
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

- 6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
- 7. Same as note (6), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



### Thermal Characteristics and Derating Information







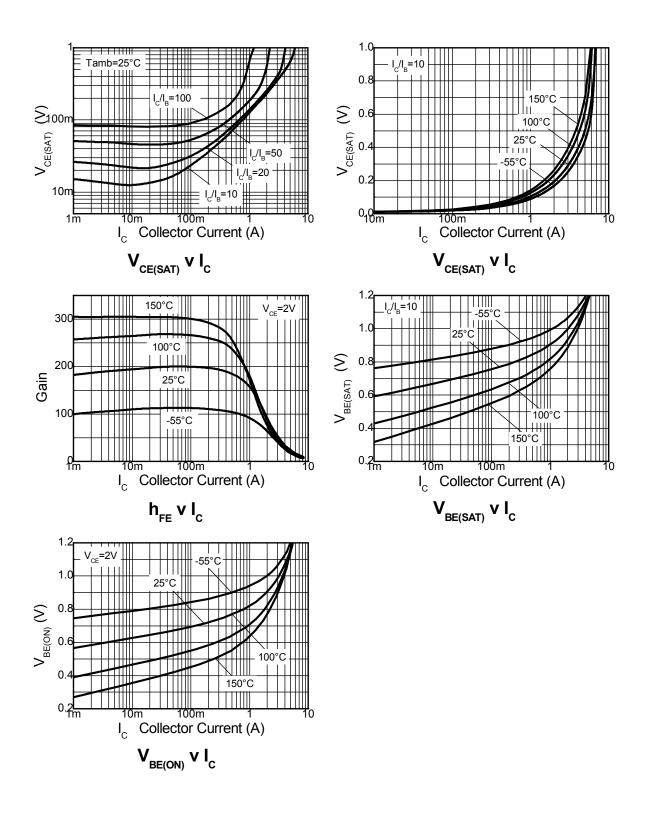
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	_	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	60	-	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7	-	-	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	1	_	-	0.1	μΑ	V <sub>CB</sub> = 60V
Collector Cut-off Current	I <sub>CBO</sub>	-	-	10		V <sub>CB</sub> = 60V, T <sub>A</sub> = 125°C
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	100	nA	V <sub>EB</sub> = 4V
Collector Emitter Seturation Voltage (Note 10)	V	-	0.12	0.3	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Collector-Emitter Saturation Voltage (Note 10)	V <sub>CE(sat)</sub>	-	0.43	0.6	V	I <sub>C</sub> = 3A, I <sub>B</sub> = 300mA
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	_	0.9	1.25	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Base-Emitter Turn-On Voltage (Note 10)	$V_{BE(on)}$	_	8.0	1.0	V	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
		70	200	_		I <sub>C</sub> = 50mA, V <sub>CE</sub> = 2V
DC Current Coin (Note 10)	h	100	200	300		I <sub>C</sub> = 500mA, V <sub>CE</sub> = 2V
DC Current Gain (Note 10)	h <sub>FE</sub> .	80	170	_	_	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
		40	80	_		I <sub>C</sub> = 2A, V <sub>CE</sub> = 2V
Current Gain-Bandwidth Product (Note 10)	f <sub>T</sub>	140	175	-	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 100mA, f = 100MHz
Switching Times	t <sub>on</sub>	_	45	_	ns	I <sub>C</sub> = 500mA, V <sub>CC</sub> = 10V,
Switching Times	t <sub>off</sub>	_	800	-	115	$I_{B1} = I_{B2} = 50 \text{mA}$
Output Capacitance (Note 10)	$C_{obo}$	-	_	30	pF	V <sub>CB</sub> = 10V, f = 1MHz

Notes: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

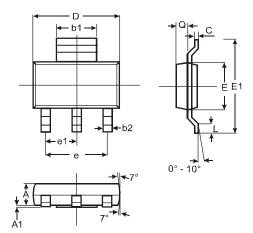






# **Package Outline Dimensions**

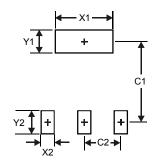
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1		_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
X1	3.3		
X2	1.2		
Y1	1.6		
Y2	1.6		
C1	6.4		
C2	2.3		





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